

117	89
Class	Subclass
ISSUE CLASSIFICATION	

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PATENT NUMBER

6488771



6488771

**U.S. UTILITY Patent Application**

 <b>O.I.P.E.</b>	<b>PATENT DATE</b> DEC 03 2017
SCANNED <u>TR3</u> . Q.A. <u>Am</u>	

APPLICATION NO.	CONT/PRIOR	CLASS 438	SUBCLASS 117	ART UNIT 1762	EXAMINER Hiteshew
09/965250			89	1765	

J. Powell  
Philip Neudeck

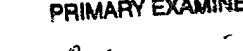
## Method for growing low-defect single crystal heteroepitaxial films

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PTO-2040  
12/99

## **ISSUING CLASSIFICATION**

Continued on Issue Slip Inside File Jacket

<input type="checkbox"/> <b>TERMINAL DISCLAIMER</b>		<b>DRAWINGS</b>			<b>CLAIMS ALLOWED</b>	
		Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
		38	52	14	52	1
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.					<b>NOTICE OF ALLOWANCE MAILED</b>	
		(Assistant Examiner)		(Date)		8-21-02
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____		<b>FELISA HITESHEW</b> <b>PRIMARY EXAMINER</b>  (Primary Examiner)			<b>ISSUE FEE</b> (W) Amount Due \$ 1280 Date Paid 9-6-02	
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.		 (Legal Instrument Examiner)			<b>ISSUE BATCH NUMBER</b> (Date)	

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